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International
IOR Rectifier

Data Sheet No. PD60028-M

IR2111(S)&(PbF)

HALF-BRIDGE DRIVER

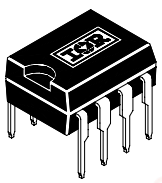
Features

- Floating channel designed for bootstrap operation
  Fully operational to +600V
  Tolerant to negative transient voltage
  dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- CMOS Schmitt-triggered inputs with pull-down
- Matched propagation delay for both channels
- Internally set deadtime
- High side output in phase with input
- Also available LEAD-FREE

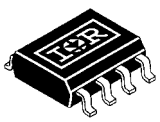
Product Summary

V_{OFFSET}	600V max.
I_O+/-	200 mA / 420 mA
V_{OUT}	10 - 20V
$t_{on/off}$ (typ.)	750 & 150 ns
Deadtime (typ.)	650 ns

Packages



8-Lead PDIP

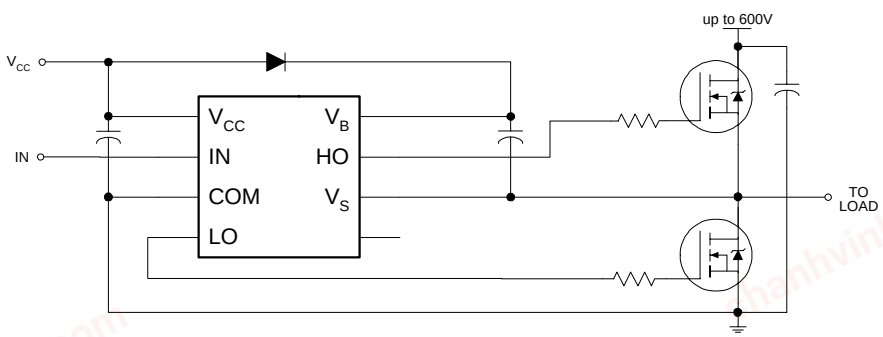


8-Lead SOIC

Description

The IR2111(S) is a high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels designed for half-bridge applications. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. Logic input is compatible with standard CMOS outputs. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Internal deadtime is provided to avoid shoot-through in the output half-bridge. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

Typical Connection



(Refer to Lead Assignments for correct pin configuration). This/These diagram(s) show electrical connections only. Please refer to our Application Notes and DesignTips for proper circuit board layout.

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Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Additional information is shown in figures 7 through 10.

Symbol	Definition		Min.	Max.	Units
V_B	High side floating supply voltage		-0.3	625	V
V_S	High side floating supply offset voltage		V_B - 25	V_B + 0.3	
V_{HO}	High side floating output voltage		V_S - 0.3	V_B + 0.3	
V_{CC}	Low side and logic fixed supply voltage		-0.3	25	
V_{LO}	Low side output voltage		-0.3	V_{CC} + 0.3	
V_{IN}	Logic input voltage		-0.3	V_{CC} + 0.3	
dV_S/dt	Allowable offset supply voltage transient (figure 2)		—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25°C$	(8 Lead PDIP)	—	1.0	W
		(8 lead SOIC)	—	0.625	
Rth_{JA}	Thermal resistance, junction to ambient	(8 lead PDIP)	—	125	°C/W
		(8 lead SOIC)	—	200	
T_J	Junction temperature		—	150	°C
T_S	Storage temperature		-55	150	
T_L	Lead temperature (soldering, 10 seconds)		—	300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	V_S + 10	V_S + 20	V
V_S	High side floating supply offset voltage	Note 1	600	
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Low side and logic fixed supply voltage	10	20	
V_{LO}	Low side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage	0	V_{CC}	
T_A	Ambient temperature	-40	125	°C

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

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Dynamic Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in figure 3.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	550	750	950	ns	V_S = 0V
t_{off}	Turn-off propagation delay	—	150	180		V_S = 600V
t_r	Turn-on rise time	—	80	130		
t_f	Turn-off fall time	—	40	65		
DT	Deadtime, LS turn-off to HS turn-on & HS turn-off to LS turn-on	480	650	820		
MT	Delay matching, HS & LS turn-on/off	—	30	—		

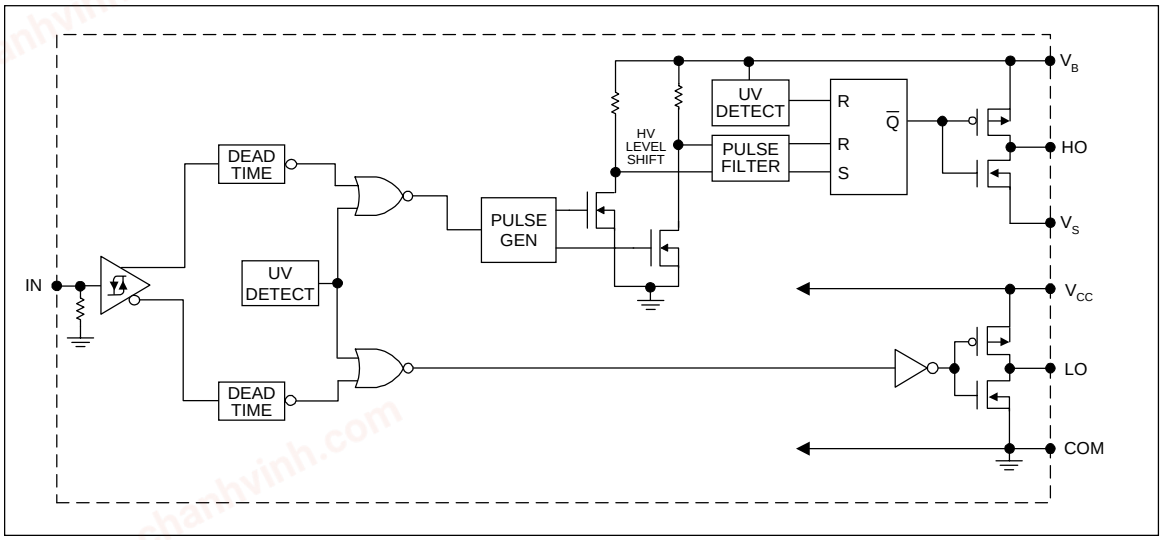
Static Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN}, V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{IH}	Logic “1” input voltage for HO & logic “0” for LO	6.4	—	—	V	V_{CC} = 10V
		9.5	—	—		V_{CC} = 15V
		12.6	—	—		V_{CC} = 20V
V_{IL}	Logic “0” input voltage for HO & logic “1” for LO	—	—	3.8		V_{CC} = 10V
		—	—	6.0		V_{CC} = 15V
		—	—	8.3		V_{CC} = 20V
V_{OH}	High level output voltage, V_{BIAS} - V_O	—	—	100	mV	I_O = 0A
V_{OL}	Low level output voltage, V_O	—	—	100		I_O = 0A
I_{LK}	Offset supply leakage current	—	—	50	µA	V_B = V_S = 600V
I_{QBS}	Quiescent V_{BS} supply current	—	50	100		V_{IN} = 0V or V_{CC}
I_{QCC}	Quiescent V_{CC} supply current	—	70	180		V_{IN} = 0V or V_{CC}
I_{IN+}	Logic “1” input bias current	—	30	50		V_{IN} = V_{CC}
I_{IN-}	Logic “0” input bias current	—	—	1.0		V_{IN} = 0V
V_{BSUV+}	V_{BS} supply undervoltage positive going threshold	7.6	8.6	9.6	V	
V_{BSUV-}	V_{BS} supply undervoltage negative going threshold	7.2	8.2	9.2		
V_{CCUV+}	V_{CC} supply undervoltage positive going threshold	7.6	8.6	9.6		
V_{CCUV-}	V_{CC} supply undervoltage negative going threshold	7.2	8.2	9.2		
I_{O+}	Output high short circuit pulsed current	200	250	—	mA	V_O = 0V, V_{IN} = V_{CC} PW ≤ 10 µs
I_{O-}	Output low short circuit pulsed current	420	500	—		V_O = 15V, V_{IN} = 0V PW ≤ 10 µs

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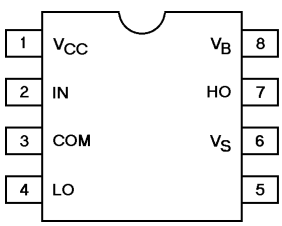
Functional Block Diagram



Lead Definitions

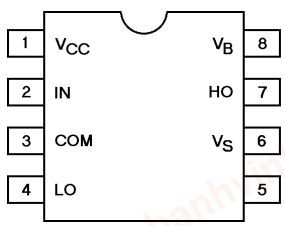
Symbol	Description
IN	Logic input for high side and low side gate driver outputs (HO & LO), in phase with HO
V_B	High side floating supply
HO	High side gate drive output
V_S	High side floating supply return
V_{CC}	Low side and logic fixed supply
LO	Low side gate drive output
COM	Low side return

Lead Assignments



8 Lead DIP

IR2111



8 Lead SOIC

IR2111S

Part Number

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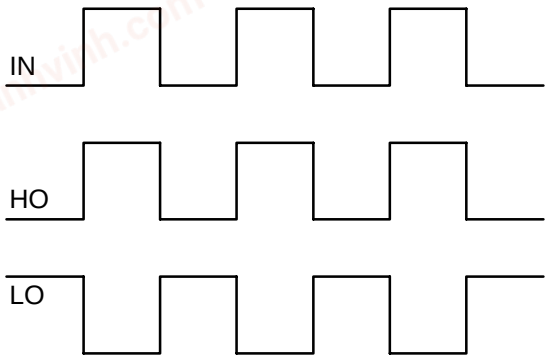


Figure 1. Input/Output Timing Diagram

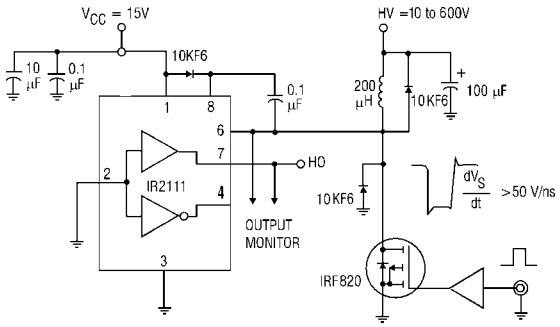


Figure 2. Floating Supply Voltage Transient Test Circuit

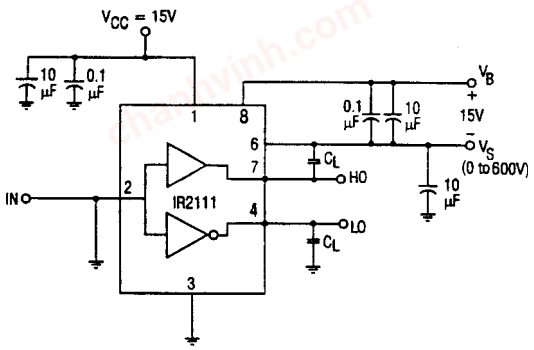


Figure 3. Switching Time Test Circuit

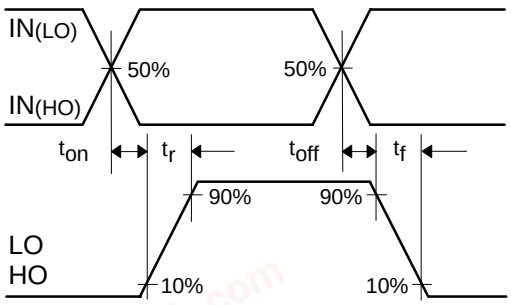


Figure 4. Switching Time Waveform Definition

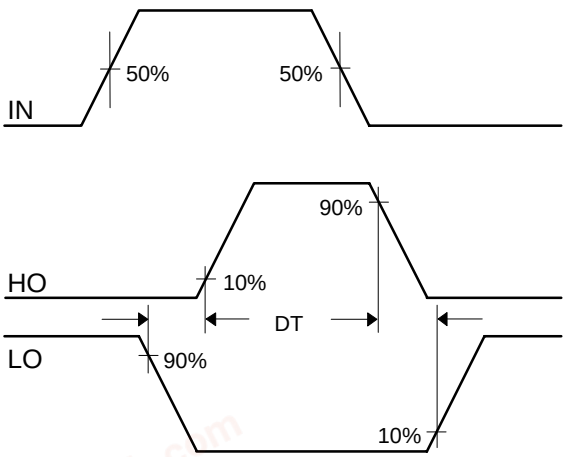


Figure 5. Deadtime Waveform Definitions

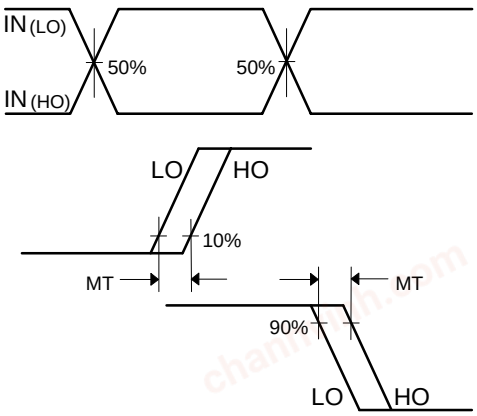


Figure 6. Delay Matching Waveform Definitions

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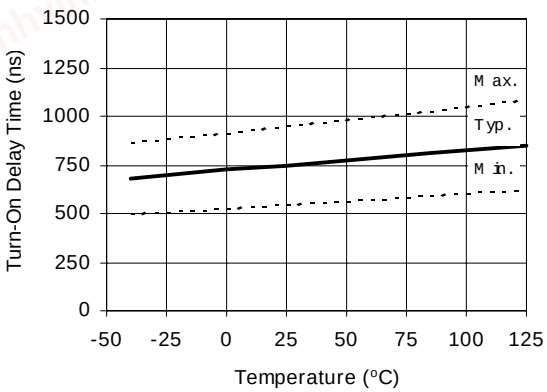


Figure 11A Turn-On Time vs Temperature

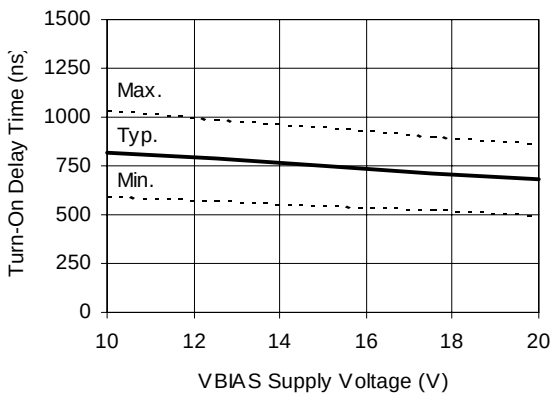


Figure 11B Turn-On Time vs Voltage

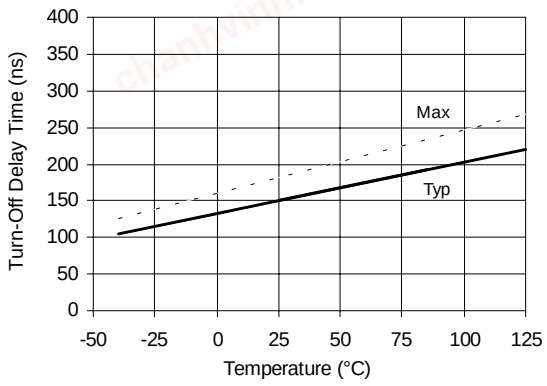


Figure 12A Turn-Off Time vs Temperature

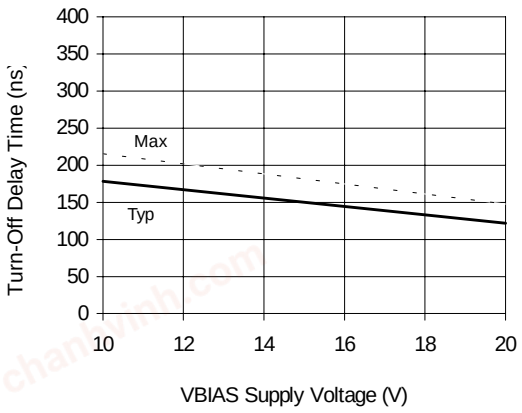


Figure 12B Turn-Off Time vs Voltage

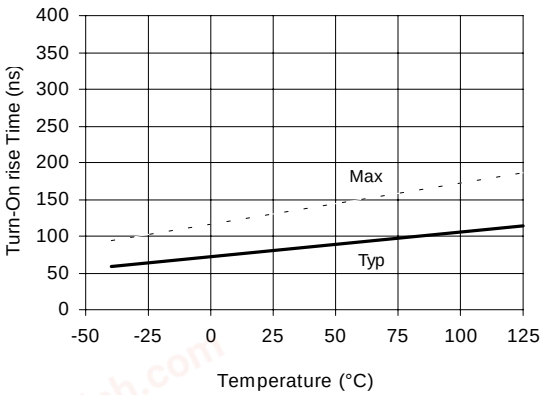


Figure 13A Turn-On RiseTime vs Temperature

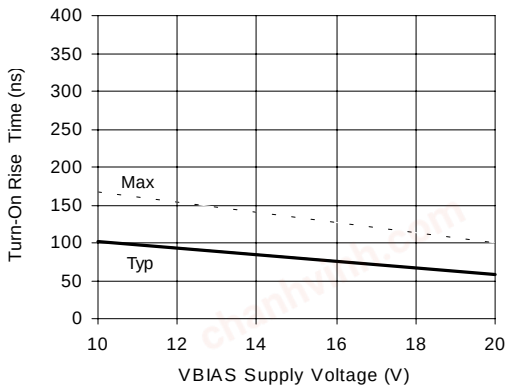


Figure 13B Turn-On RiseTime vs Voltage

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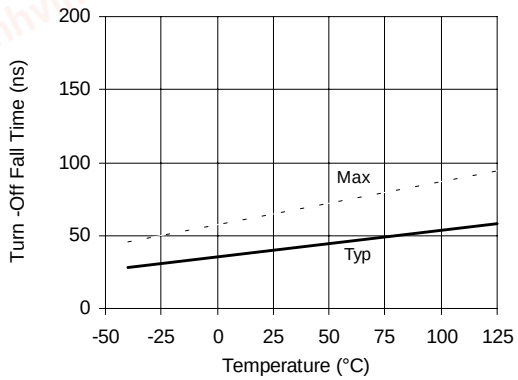


Figure 14A Turn-Off Fall Time vs Temperature

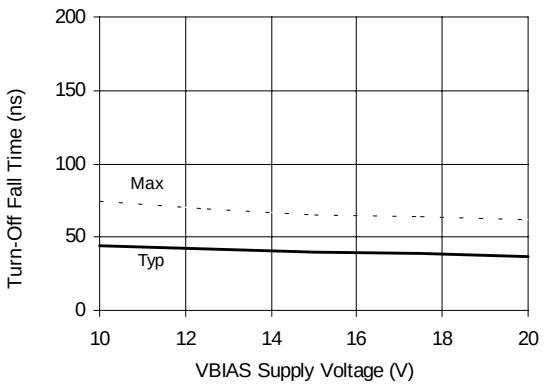


Figure 14B Turn-Off Fall Time vs Voltage

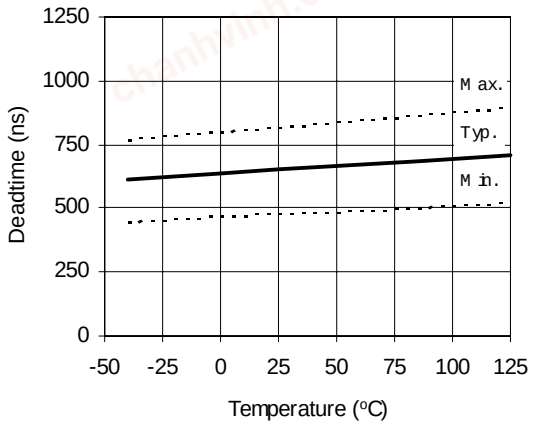


Figure 15A Dead Time vs Temperature

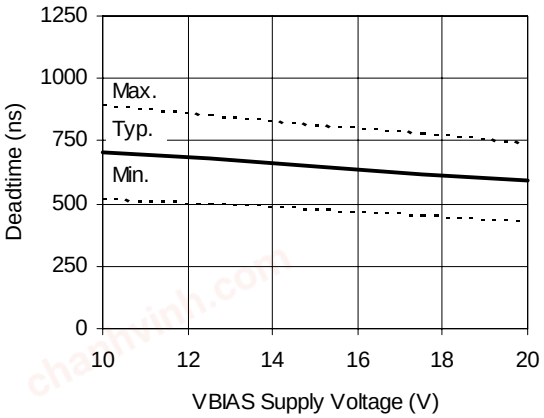


Figure 15B Dead Time vs Voltage

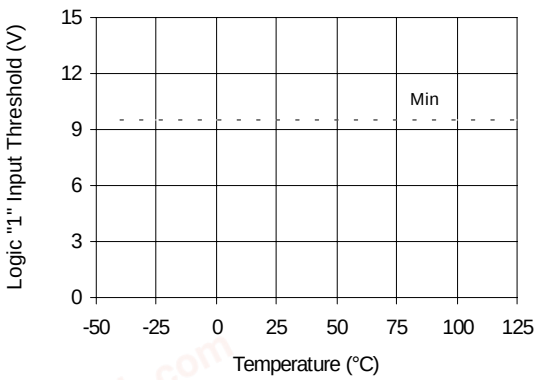


Figure 16A Logic "I" Input voltage for HO & Logic "0" for LO vs Temperature

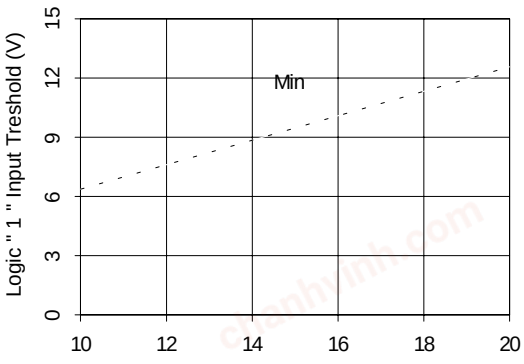


Figure 16B Logic "I" Input voltage for HO & Logic "0" for LO vs Voltage

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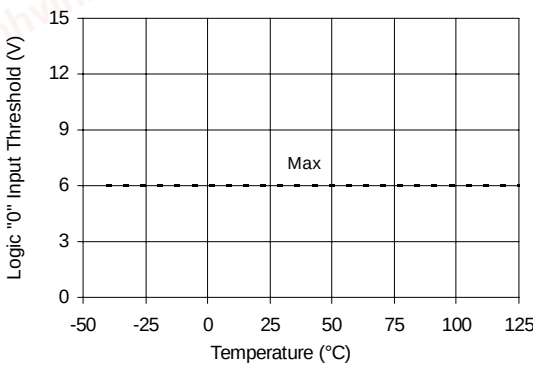


Figure 17A Logic "0" Input voltage for HO & Logic "I" for LO vs Temperature

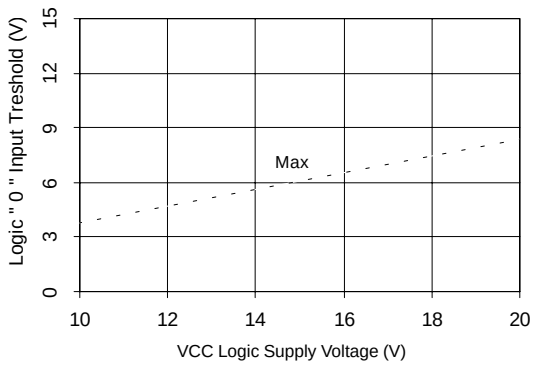


Figure 17B Logic "0" Input voltage for HO & Logic "I" for LO vs Voltage

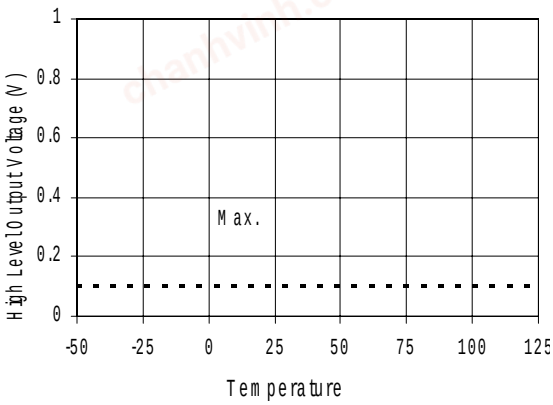


Figure 18A. High Level Output vs. Temperature

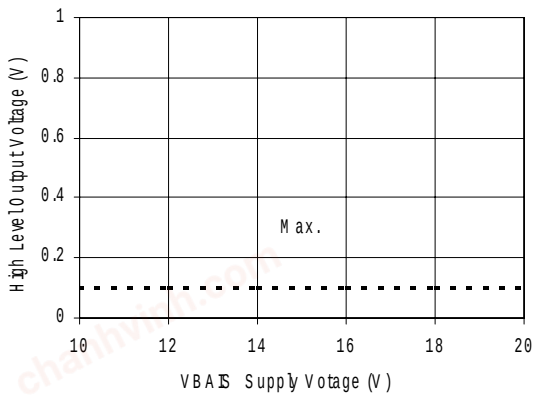


Figure 18B. High Level Output vs. Voltage

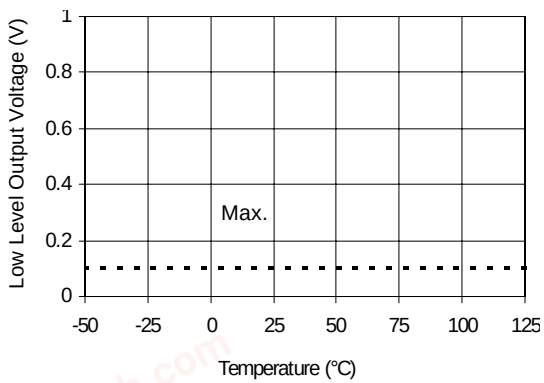


Figure 19A. Low Level Output vs. Temperature

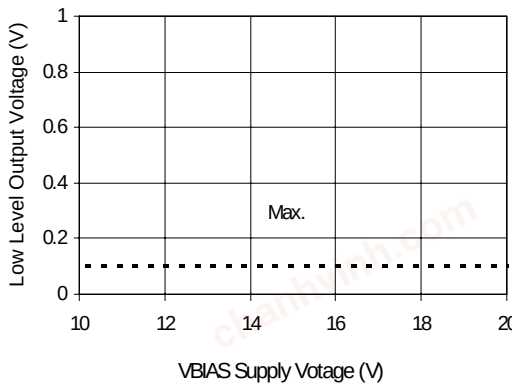


Figure 19B. Low Level Output vs. Voltage

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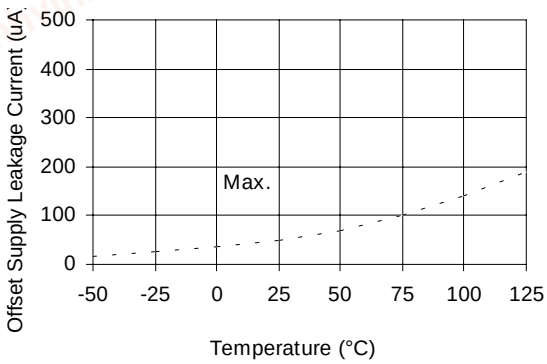


Figure 20A Offset Supply Current vs Temperature

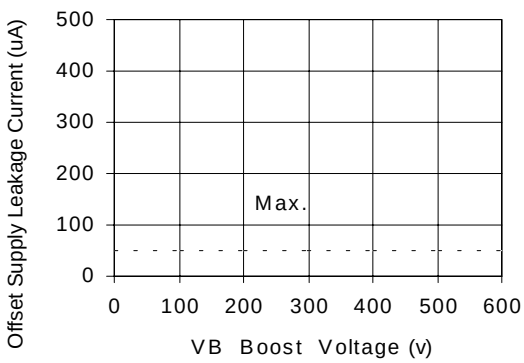


Figure 20B Offset Supply Current vs Voltage

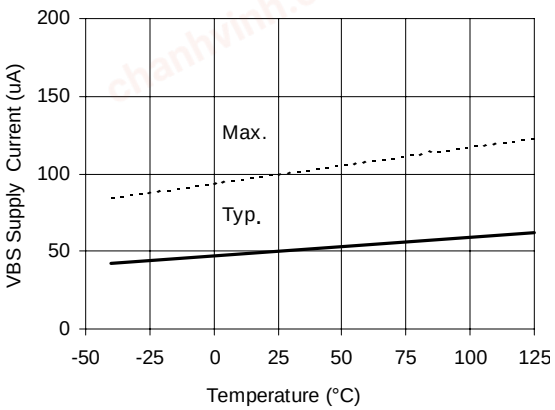


Figure 21A VBS Supply Current vs Temperature

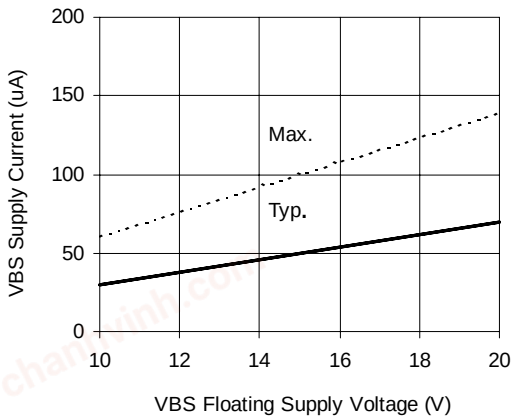


Figure 21B VBS Supply Current vs Voltage

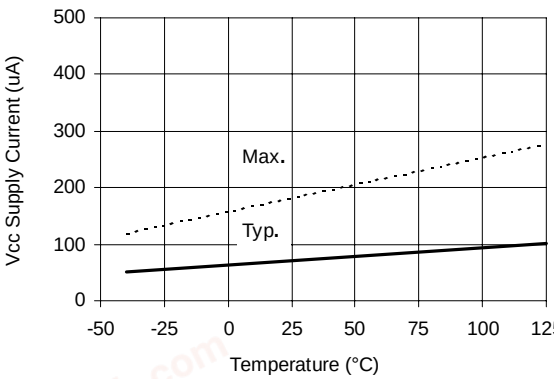


Figure 22A VCC Supply Current vs Temperature

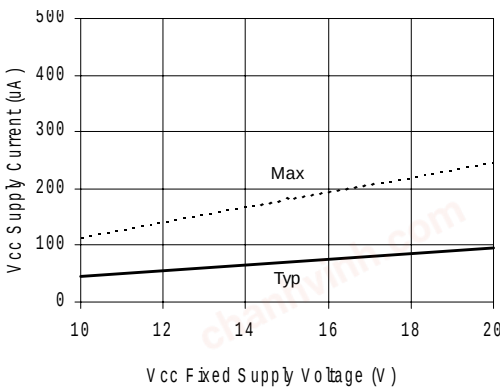


Figure 22B VCC Supply Current vs Voltage

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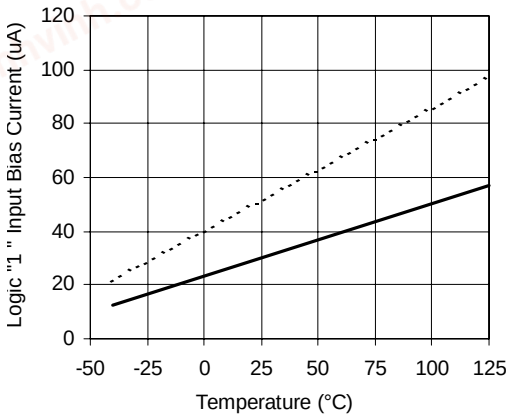


Figure 23A Logic “1” Input Current vs Temperature

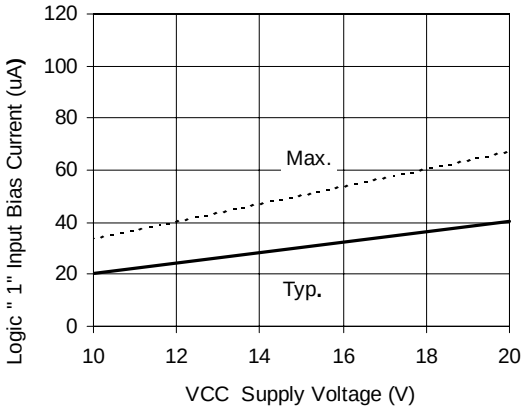


Figure 23B Logic “1” Input Current vs V_{CC} Voltage

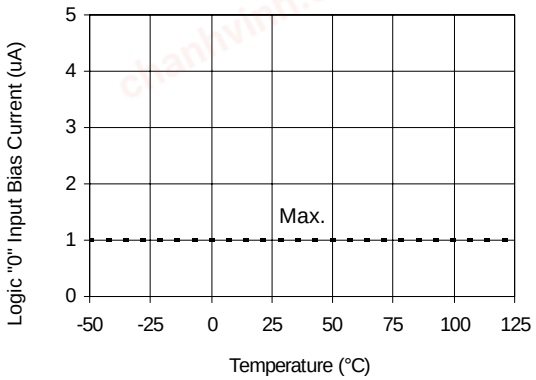


Figure 24A. Logic “0” Input Current vs. Temperature

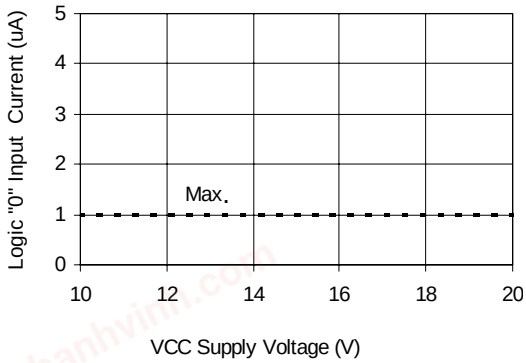


Figure 24B. Logic “0” Input Current vs. V_{CC} Voltage

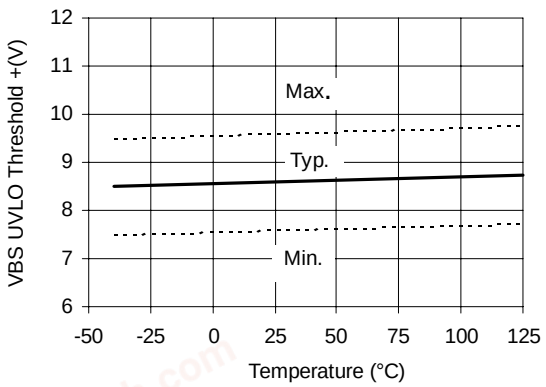


Figure 25 VBS Undervoltage Threshold (+) vsTemperature

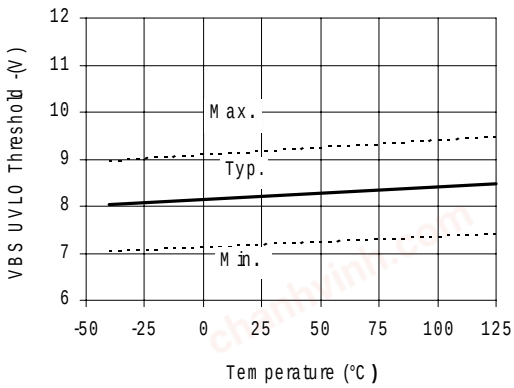


Figure 26 VBS Undervoltage Threshold (-) vsTemperature

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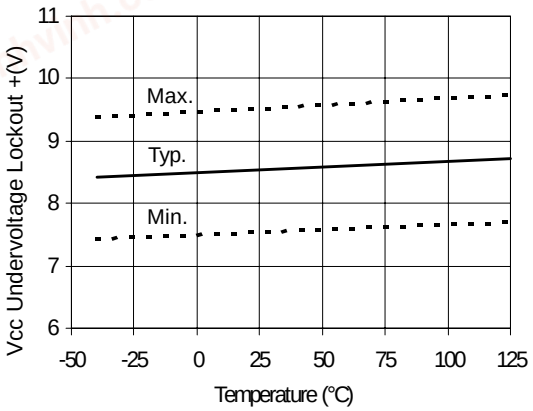


Figure 27 Vcc Undervoltage (-) vs Temperature

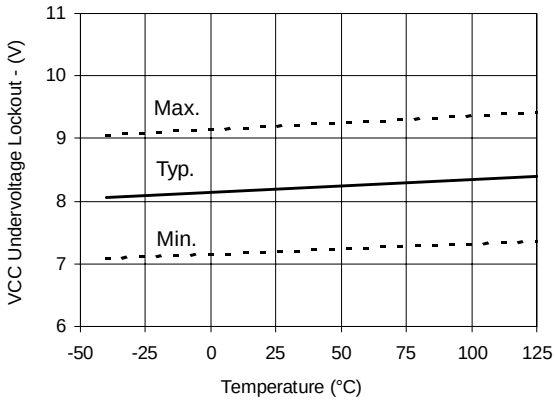


Figure 28 Vcc Undervoltage (-) vs Temperature

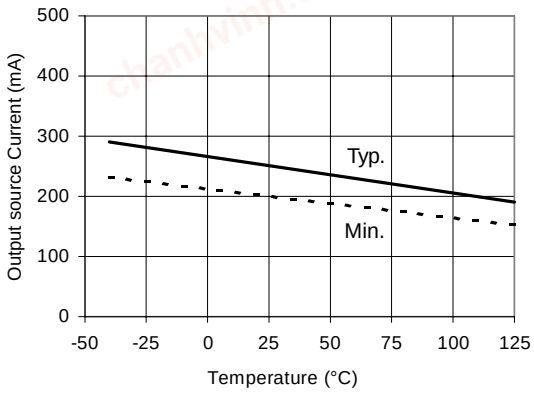


Figure 29A Output Source Current vs Temperature

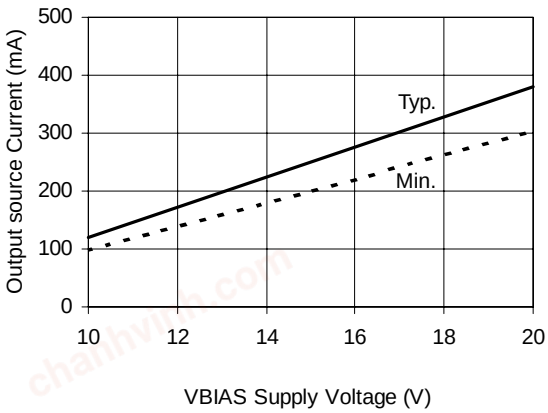


Figure 29B Output Source Current vs Voltage

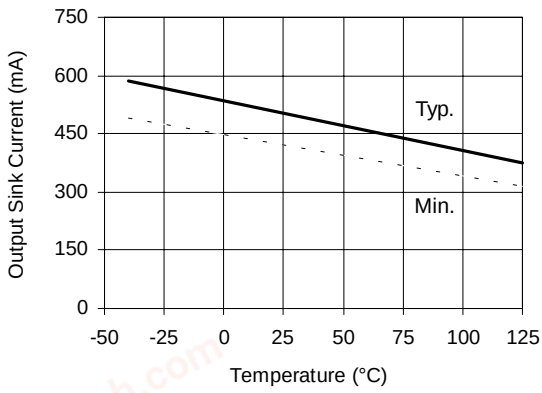


Figure 30A Output Sink Current vs Temperature

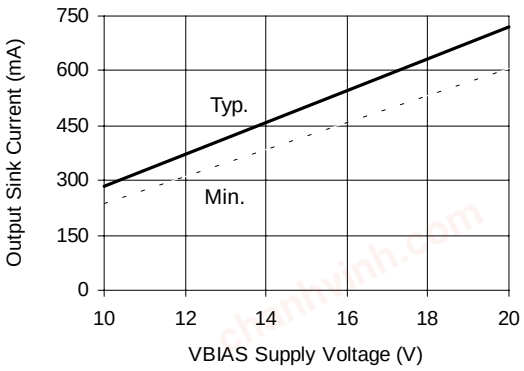


Figure 30B Output Sink Current vs Voltage

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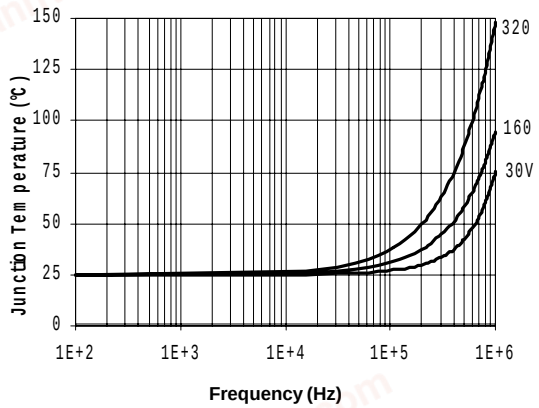


Figure 31. IR2111 T_J vs. Frequency (IRFBC20)
R_{GATE} = 33Ω, V_{CC} = 15V

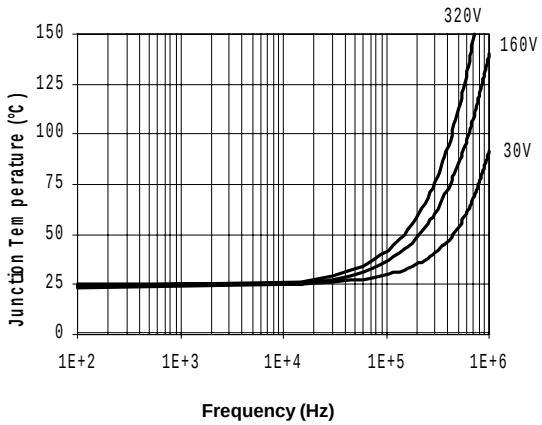


Figure 32. IR2111 T_J vs. Frequency (IRFBC30)
R_{GATE} = 22Ω, V_{CC} = 15V

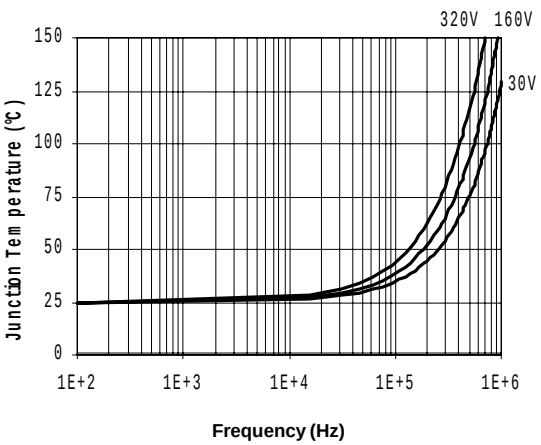


Figure33. IR2111 T_J vs. Frequency (IRFBC40)
R_{GATE} = 15Ω, V_{CC} = 15V

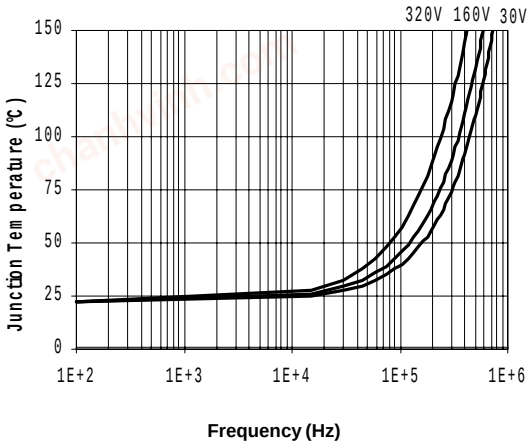


Figure 34. IR2111 T_J vs. Frequency (IRFPC50)
R_{GATE} = 10Ω, V_{CC} = 15V

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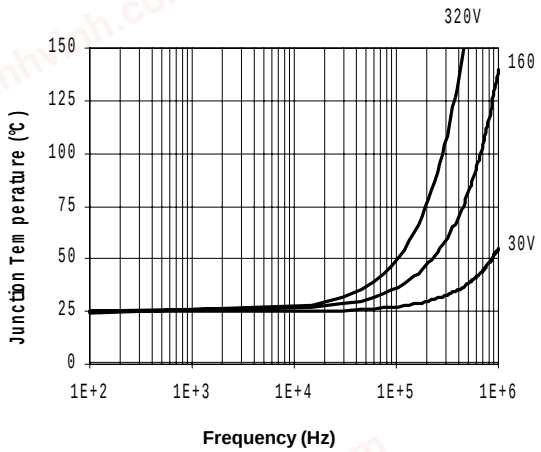


Figure 35. IR2111S T_J vs. Frequency (IRFBC20)
R_{GATE} = 33Ω, V_{CC} = 15V

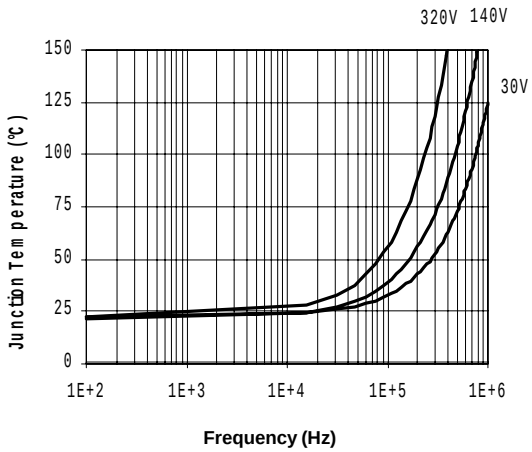


Figure 36. IR2111S T_J vs. Frequency (IRFBC30)
R_{GATE} = 22Ω, V_{CC} = 15V

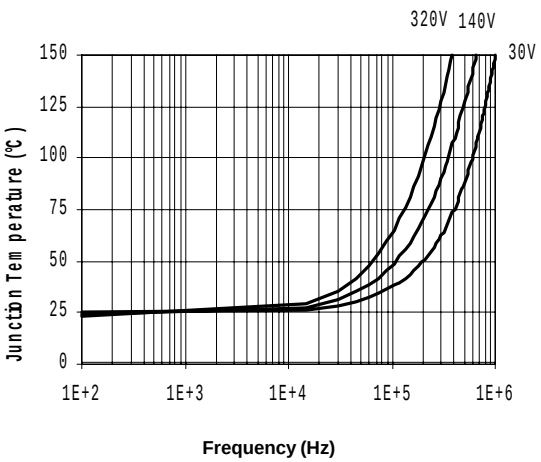


Figure 37. IR2111S T_J vs. Frequency (IRFBC40)
R_{GATE} = 15Ω, V_{CC} = 15V

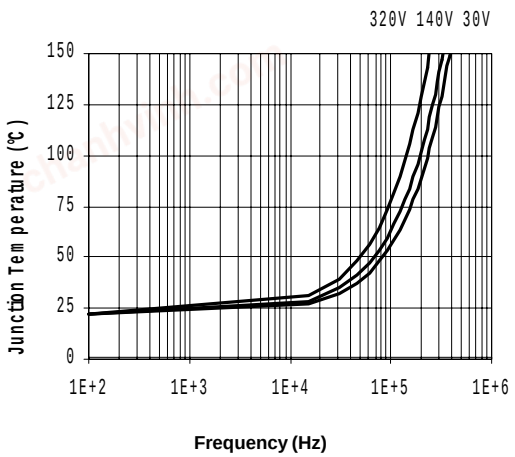
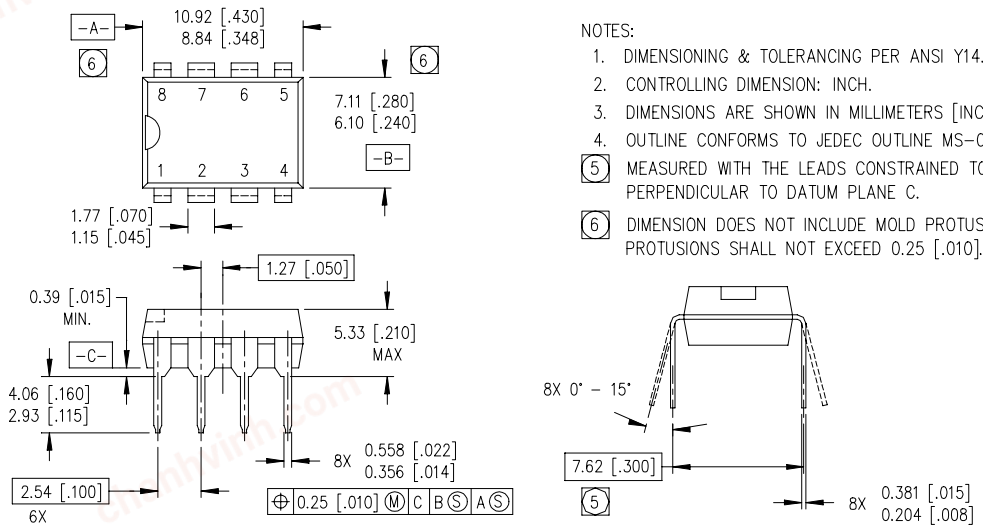


Figure 38. IR2111S T_J vs. Frequency (IRFPC50)
R_{GATE} = 10Ω, V_{CC} = 15V

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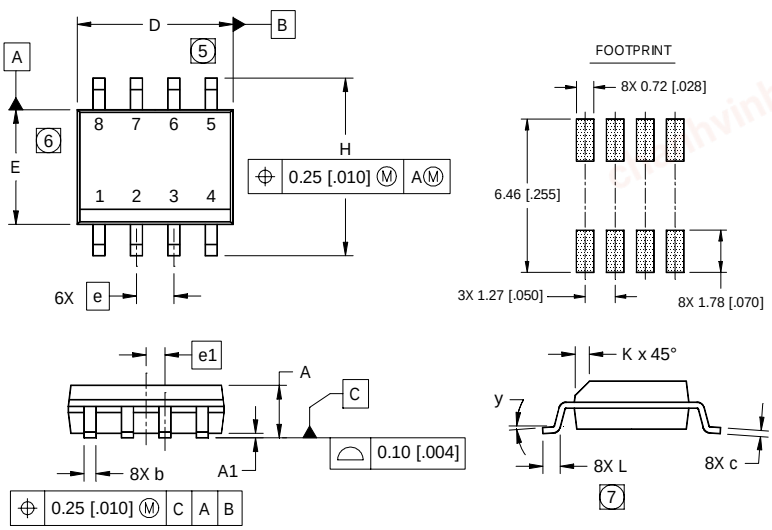
Case outlines



NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M–1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS–001AB.
5. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.25 [.010].

8-Lead PDIP

01-6014
01-3003 01 (MS-001AB)



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
c	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
e	.050 BASIC		1.27 BASIC	
e 1	.025 BASIC		0.635 BASIC	
H	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
y	0°	8°	0°	8°

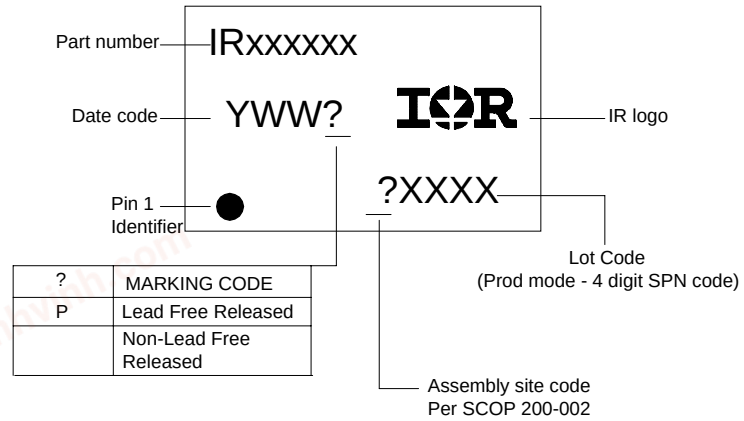
NOTES:
1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
5. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 [.006].
6. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 [.010].
7. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

8-Lead SOIC

01-6027
01-0021 11 (MS-012AA)

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LEADFREE PART MARKING INFORMATION



?	MARKING CODE
P	Lead Free Released
	Non-Lead Free Released

ORDER INFORMATION

Basic Part (Non-Lead Free)
8-Lead PDIP IR2111 order IR2111
8-Lead SOIC IR2111S order IR2111S

Leadfree Part
8-Lead PDIP IR2111 order IR2111PbF
8-Lead SOIC IR2111S order IR2111SPbF